TEXAS INSTRUMENTS
Data sheet acquired from Harris Semiconductor
SCHS062A – Revised March 2002

CD4089B Types

CMOS Binary Rate Multiplier

High-Voltage Types (20-Volt Rating)

■ CD4089B is a low-power 4-bit digital rate multiplier that provides an output pulse rate that is the clock-input-pulse rate multiplied by 1/16 times the binary input. For example, when the binary input number is 13, there will be 13 output pulses for every 16 input pulses. This device may be used in conjunction with an up/down counter and control logic used to perform arithmetic operations (adds, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigometric functions, A/D and D/A conversions, and frequency division.

For words of more than 4 bits, CD4089B devices may be cascaded in two different modes: an Add mode and a Multiply mode (see Figs. 14 and 15). In the Add mode some of the gaps left by the more significant unit at the count of 15 are filled in by the less significant units. For example, when two units are cascaded in the Add mode and programmed to 11 and 13, respectively, the more significant unit will have 11 output pulses for every 16 input pulses and the other unit will have 13 output pulses for every 256 input pulses for a total of

$$\frac{11}{16}+\frac{13}{256}=\frac{189}{256}$$

In the Multiply mode the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second multiplier. Thus the output rate will be

$$\frac{11}{16}\times\frac{13}{16}=\frac{143}{256}$$

Features:

- Cascadable in multiples of 4-bits
- Set to "15" input and "15" detect output
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =
  1 V at V_{DD} = 5 V
  2 V at V_{DD} = 10 V
  2.5 V at V_{DD} = 15 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

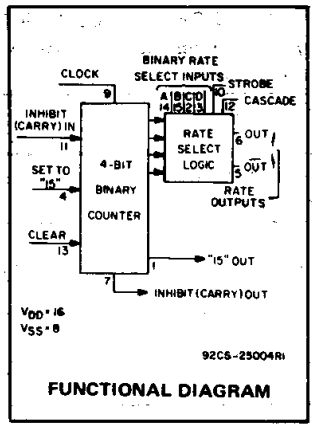
Applications:

- Numerical control
- Instrumentation
- Digital filtering
- Frequency synthesis

The CD4089B has an internal synchronous 4-bit counter which, together with one of the four binary input bits, produces pulse trains as shown in Fig. 2.

If more than one binary input bit is high, the resulting pulse train is a combination of the separate pulse trains as shown in Fig. 2.

The CD4089B types are supplied in 16-lead ceramic dual-in-line packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline package (NSR suffix), and in chip form (H suffix).



FUNCTIONAL DIAGRAM

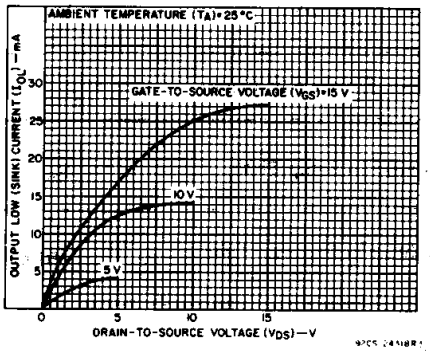


Fig. 1 — Typical output low (sink) current characteristics.

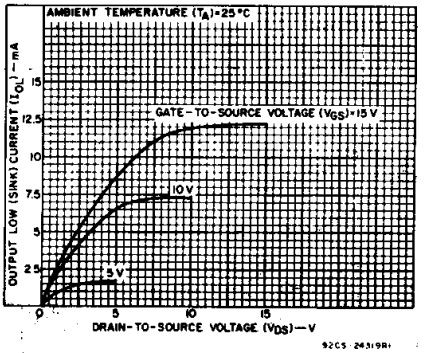


Fig. 2 - Minimum output low (sink) current characteristics.

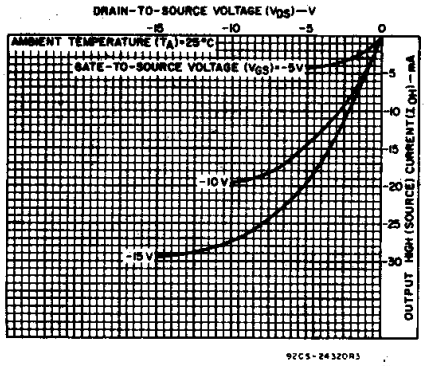


Fig. 3 — Typical output high (source) current characteristics.

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

RECOMMENDED OPERATING CONDITIONS at T_A = 25°C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC		V_{DD} (V)	LIMITS Min.	LIMITS Max.	UNITS
Supply-Voltage Range (For T_A = Full Package-Temperature Range)			3	18	V
Set or Clear Pulse Width,	t_W	5	160	–	ns
		10	90	–	
		15	60	–	
Clock Pulse Width,	t_W	5	330	–	ns
		10	170	–	
		15	100	–	
Clock Frequency,	f_{CL}	5		1.2	MHz
		10	dc	2.5	
		15		3.5	
Clock Rise or Fall Time,	t_{rCL} or t_{fCL}	5, 10,15	–	15	μs
Inhibit In Setup Time,	t_{SU}	5	100	–	ns
		10	40	–	
		15	20	–	
Inhibit In Removal Time,	t_{REM}	5	240	–	ns
		10	130	–	
		15	110		
Set Removal Time,	t_{REM}	5	150	–	ns
		10	80	–	
		15	50	–	
Clear Removal Time,	t_{REM}	5	60	–	ns
		10	40	–	
		15	30	–	

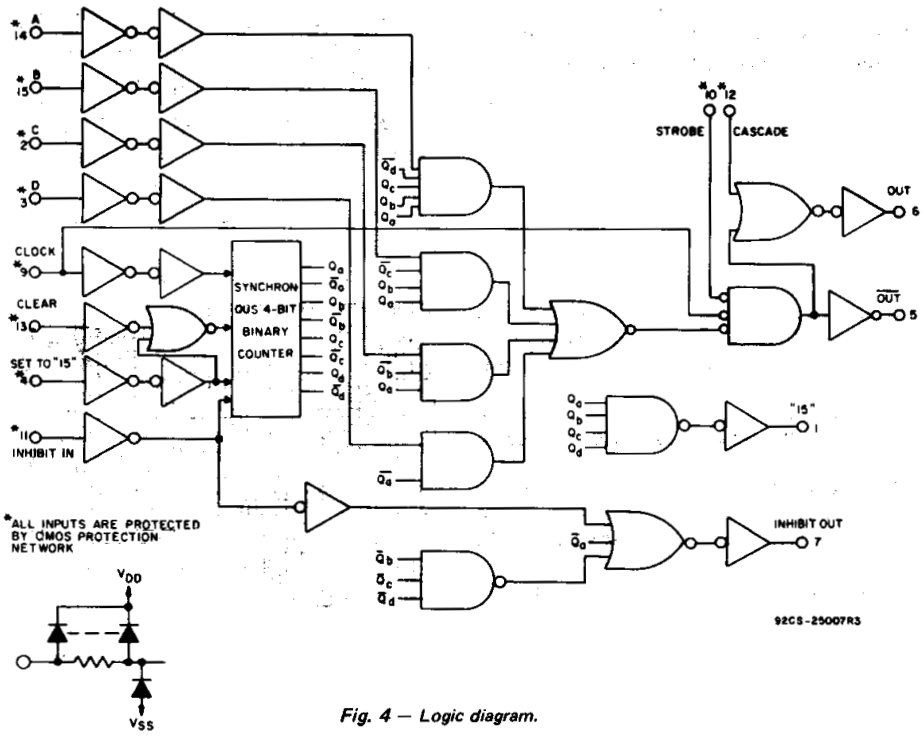


Fig. 4 — Logic diagram.

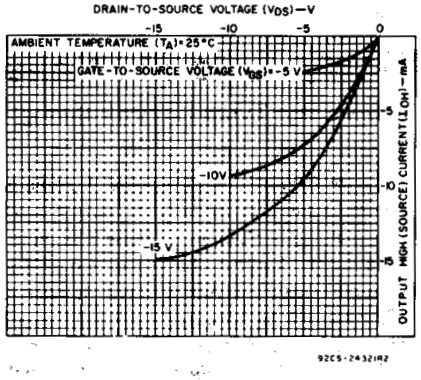


Fig. 5 — Minimum output high (source) current characteristics.

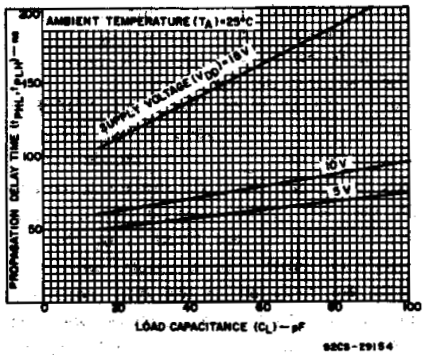


Fig. 6 — Typical propagation delay time as a function of load capacitance (Clock or Strobe to Out).

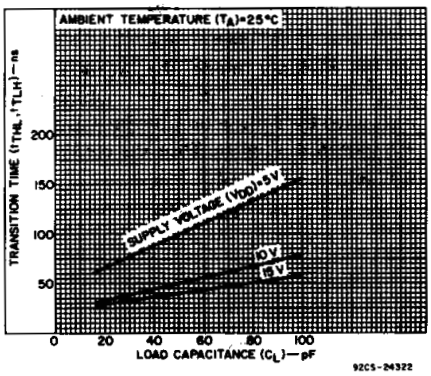


Fig. 7 — Typical transition time as a function of load capacitance.

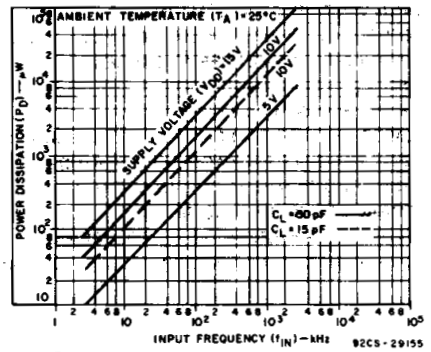


Fig. 8 — Typical dynamic power dissipation as a function of input frequency.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C;
Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 kΩ

CHARACTERISTIC	TEST CONDITIONS V_{DD} V	LIMITS Min.	LIMITS Typ.	LIMITS Max.	UNITS
Propagation Delay Time, t_{PHL}, t_{PLH} Clock to $\overline{Out}$	5	–	110	220	ns
	10	–	55	110	
	15	–	45	90	
Clock or Strobe to Out	5	–	150	300	
	10	–	75	150	
	15	–	60	120	
Clock to Inhibit Out High Level to Low Level	5	–	360	720	ns
	10	–	160	320	
	15	–	110	220	
Low Level to High Level	5	–	250	500	ns
	10	–	100	200	
	15	–	75	150	
Clear to Out	5	–	380	760	ns
	10	–	175	350	
	15	–	130	260	
Clock to "9" or "15" Out	5	–	300	600	ns
	10	–	125	250	
	15	–	90	180	
Cascade to Out	5	–	90	180	ns
	10	–	45	90	
	15	–	35	70	
Inhibit In to Inhibit Out	5	–	160	320	ns
	10	–	75	150	
	15	–	55	110	
Set to Out	5	–	330	660	
	10	–	150	300	
	15	–	110	220	
Transition Time, t_{THL}, t_{TLH}	5	–	100	200	ns
	10	–	50	100	
	15	–	40	80	
Maximum Clock Frequency, f_{CL}	5	1.2	2.4	–	MHz
	10	2.5	5	–	
	15	3.5	7	–	
Minimum Clock Pulse Width, t_W	5	–	165	330	ns
	10	–	85	170	
	15	–	50	100	
Clock Rise or Fall Time, t_{rCL}, t_{fCL}	5	–	–	15	μs
	10	–	–	15	
	15	–	–	15	
Minimum Set or Clear Pulse Width, t_W	5	–	80	160	ns
	10	–	45	90	
	15	–	30	60	
Minimum Inhibit-In Setup Time, t_{SU}	5	–	50	100	ns
	10	–	20	40	
	15	–	10	20	
Minimum Inhibit In Removal Time, t_{REM}	5	–	120	240	ns
	10	–	65	130	
	15	–	55	110	

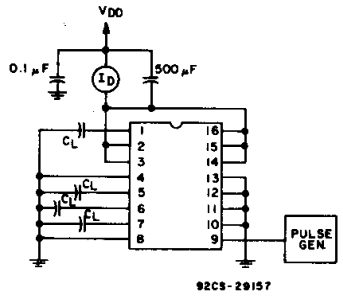


Fig. 9 — Dynamic power dissipation test circuit.

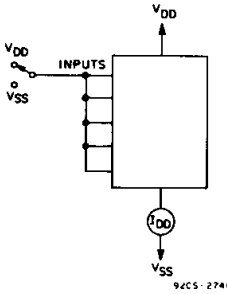


Fig. 10 — Quiescent device current test circuit.

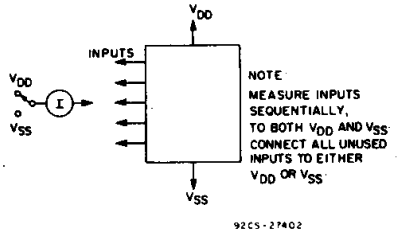


Fig. 11 — Input-current test circuit.

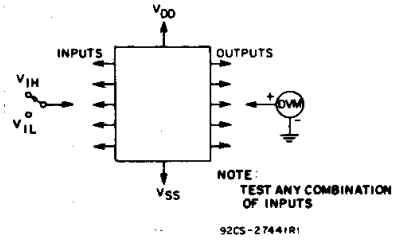
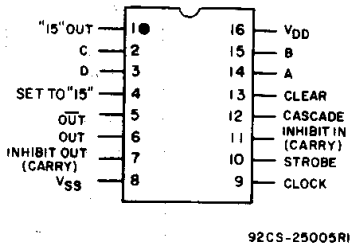


Fig. 12 — Input-voltage test circuit.



TOP VIEW

TERMINAL ASSIGNMENT

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C (cont'd)
Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 kΩ

CHARACTERISTIC	TEST CONDITIONS		LIMITS			UNITS
		V_{DD} V	Min.	Typ.	Max.	
Minimum Set Removal Time, t_{REM}		5	–	75	150	ns
		10	–	40	80	
		15	–	25	50	
Minimum Clear Removal Time, t_{REM}		5	–	30	60	ns
		10	–	20	40	
		15	–	15	30	
Input Capacitance, C_{IN}	Any Input	–	–	5	7.5	pF

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
								+25			
	V_O (V)	V_{IN} (V)	V_{DD} (V)	–55	–40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I_{DD} Max.	–	0,5	5	5	5	150	150	–	0.04	5	μA
	–	0,10	10	10	10	300	300	–	0.04	10	
	–	0,15	15	20	20	600	600	–	0.04	20	
	–	0,20	20	100	100	3000	3000	–	0.08	100	
Output Low (Sink) Current I_{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	–	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	–	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	–	
Output High (Source) Current, I_{OH} Min.	4.6	0,5	5	–0.64	–0.61	–0.42	–0.36	–0.51	–1	–	
	2.5	0,5	5	–2	–1.8	–1.3	–1.15	–1.6	–3.2	–	
	9.5	0,10	10	–1.6	–1.5	–1.1	–0.9	–1.3	–2.6	–	
	13.5	0,15	15	–4.2	–4	–2.8	–2.4	–3.4	–6.8	–	
Output Voltage: Low-Level, V_{OL} Max.	–	0,5	5	0.05				–	0	0.05	V
	–	0,10	10	0.05				–	0	0.05	
	–	0,15	15	0.05				–	0	0.05	
Output Voltage: High-Level, V_{OH} Min.	–	0,5	5	4.95				4.95	5	–	
	–	0,10	10	9.95				9.95	10	–	
	–	0,15	15	14.95				14.95	15	–	
Input Low Voltage V_{IL} Max.	0.5,4.5	–	5	1.5				–	–	1.5	V
	1,9	–	10	3				–	–	3	
	1.5,13.5	–	15	4				–	–	4	
Input High Voltage, V_{IH} Min.	0.5,4.5	–	5	3.5				3.5	–	–	
	1,9	–	10	7				7	–	–	
	1.5,13.5	–	15	11				11	–	–	
Input Current I_{IN} Max.	–	0,18	18	±0.1	±0.1	±1	±1	–	$\pm 10^{-5}$	±0.1	μA

TRUTH TABLE

INPUTS										OUTPUTS			
Number of Pulses or Input Logic Level (0 = Low; 1 = High; X = Don't Care)										Number of Pulses or Output Logic Level (L = Low; H = High)			
D	C	B	A	CLK	INH IN	STR	CAS	CLR	SET	OUT	$\overline{OUT}$	INH OUT	"15" OUT
0	0	0	0	16	0	0	0	0	0	L	H	1	1
0	0	0	1	16	0	0	0	0	0	1	1	1	1
0	0	1	0	16	0	0	0	0	0	2	2	1	1
0	0	1	1	16	0	0	0	0	0	3	3	1	1
0	1	0	0	16	0	0	0	0	0	4	4	1	1
0	1	0	1	16	0	0	0	0	0	5	5	1	1
0	1	1	0	16	0	0	0	0	0	6	6	1	1
0	1	1	1	16	0	0	0	0	0	7	7	1	1
1	0	0	0	16	0	0	0	0	0	8	8	1	1
1	0	0	1	16	0	0	0	0	0	9	9	1	1
1	0	1	0	16	0	0	0	0	0	10	10	1	1
1	0	1	1	16	0	0	0	0	0	11	11	1	1
1	1	0	0	16	0	0	0	0	0	12	12	1	1
1	1	0	1	16	0	0	0	0	0	13	13	1	1
1	1	1	0	16	0	0	0	0	0	14	14	1	1
1	1	1	1	16	0	0	0	0	0	15	15	1	1
X	X	X	X	16	1	0	0	0	0	†	†	H	†
X	X	X	X	16	0	1	0	0	0	L	H	1	1
X	X	X	X	16	0	0	1	0	0	H	*	1	1
1	X	X	X	16	0	0	0	1	0	16	16	H	L
0	X	X	X	16	0	0	0	1	0	L	H	H	L
X	X	X	X	16	0	0	0	X	1	L	H	L	H

* Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).
† Depends on internal state of counter.

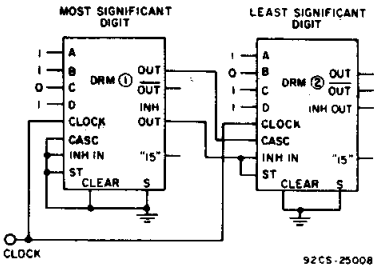


Fig. 13 – Two CD4089B's cascaded in the "Add" mode with a preset number of 189 $\left(\frac{11}{16}+\frac{13}{256}=\frac{189}{256}\right)$

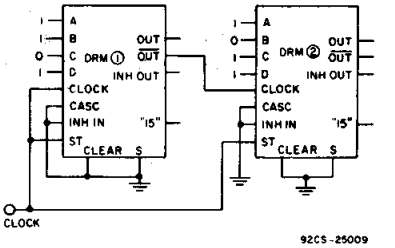
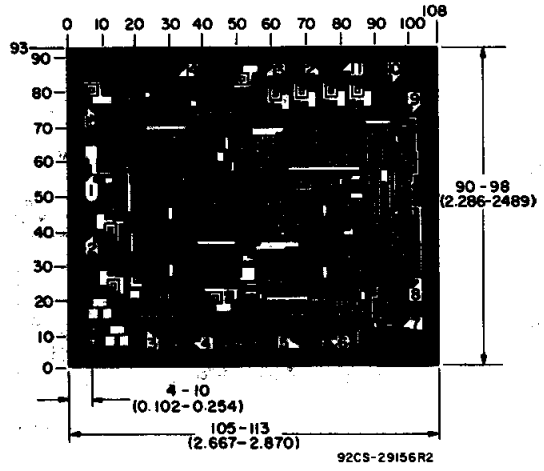


Fig. 14 – Two CD4089B's cascaded in the "Multiply" mode with a preset number of 143 $\left(\frac{11}{16}\times\frac{13}{16}=\frac{143}{256}\right)$.



Dimensions and Pad Layout for CD4089BH

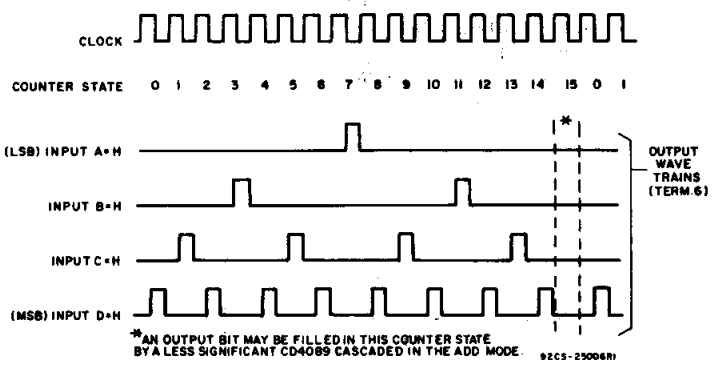


Fig. 15 – Timing diagram.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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